Understanding Current Sensing Applications & How to Choose the Right Device

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Outline & Presentation Goals

- Outline
 - Fundamentals
 - Devices
- Goals of this presentation
 - Select a current sensing topology (direct vs. indirect, high vs. low-side, etc.)
 - Select the appropriate device (op amp, difference amp, inst. amp, or CSM?)

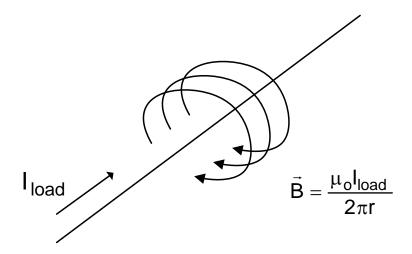


Fundamentals



Indirect Sensing

- Based on Ampere's and Faraday's Laws
- Noninvasive
- Inherently isolated
- No power lost by the system
- Recommend
 - Very high currents (e.g. >100A)
 - Very high voltage
 - Very dynamic load currents
 - Isolation required



Indirect Sensing-Solutions

- Hall Effect Sensor
 - ADS1208, ADS1205, ADS7861, ADS8361, ADS8365
 - Application note SLAA286

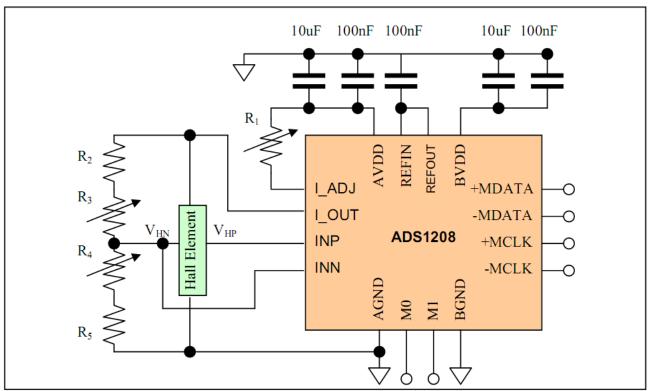


Figure 3: Hall module using the ADS1208



Type T60404M-4645-X600 T60404M-4645-X601

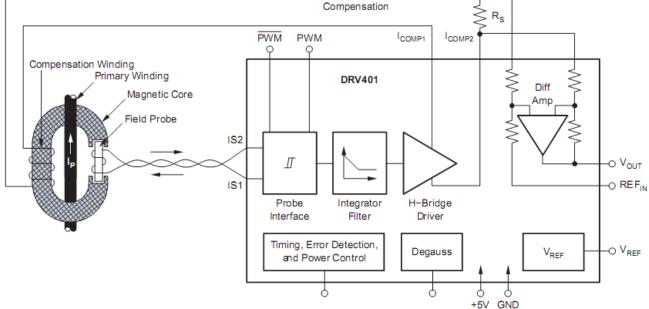
Indirect Sensing-Solutions

VAC Sensor

- DRV401 is a custom solution for VAC Sensors
- Combine with SAR ADC (e.g. ADS8509)
- Less sensitive to temperature drift and initial offset than Hall sensor solutions

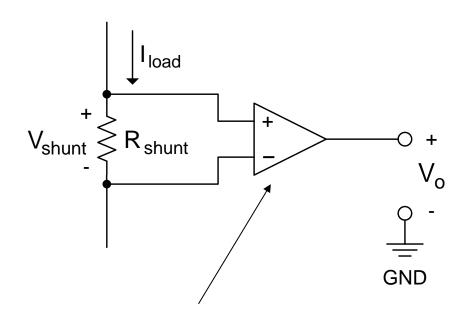


Patents Pending.





Direct Sensing



Differential Amplifier

- Based on Ohm's Law
- Shunt resistor in series with load
- Invasive
- Power dissipated by Rshunt
- Sensing circuit not isolated from system load
- Recommend
 - Smaller currents (<100A)
 - System can tolerate power loss
 - Low voltage
 - Load current not very dynamic
 - Isolation not required (though it can be accomplished)

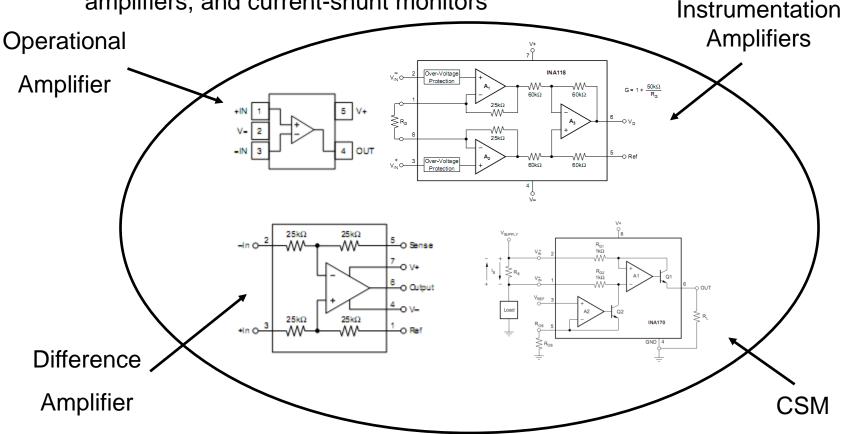


Differential Input Amplifier

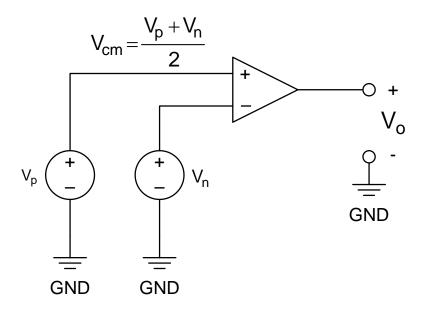
Differential input amplifiers are devices/circuits that can input and amplify differential signals while suppressing common-mode signals

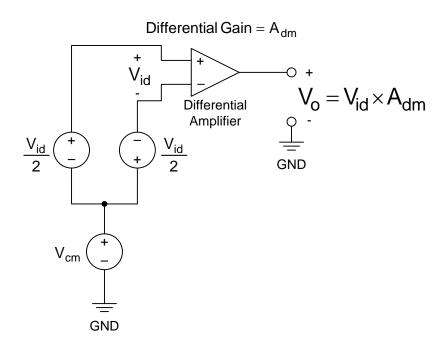
- This includes operational amplifiers, instrumentation amplifiers, difference

amplifiers, and current-shunt monitors



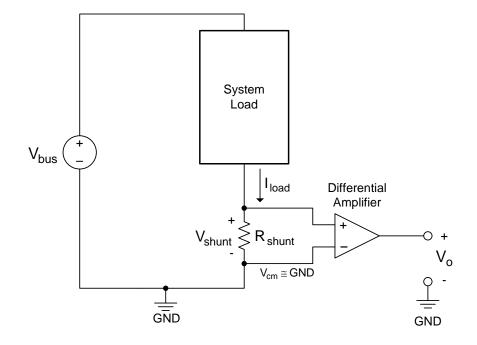
Common-Mode Voltage



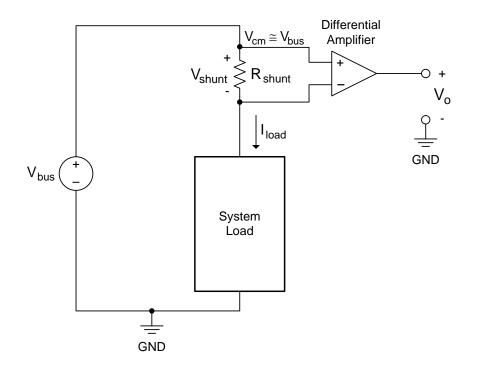


Low-Side Sensing

- Shunt resistor placed between the system load and ground
- Pros
 - Vcm≈0V
 - Straightforward
 - Inexpensive (may use an op amp)
- Cons
 - Can't detect load shorts to ground
 - Single-ended measurement (stay tuned)
 - System GND is now Iload*Rshunt



High-Side Sensing

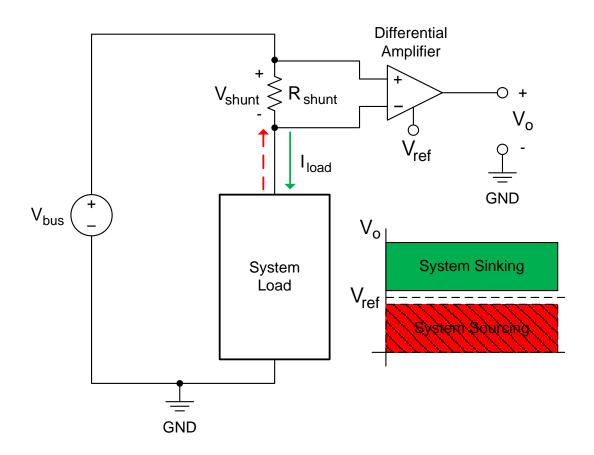


- Shunt resistor placed between supply (Vbus) and system load
 - Pros
 - · Can detect load shorts to ground
 - · Monitors current directly from source
 - Cons
 - Vcm≈Vbus



Directionality

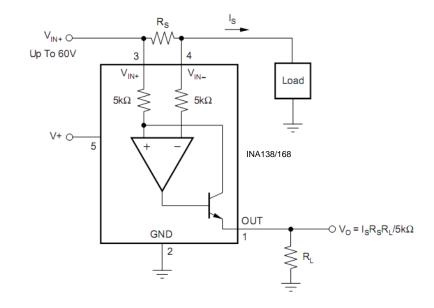
Application may require sensing current in both directions

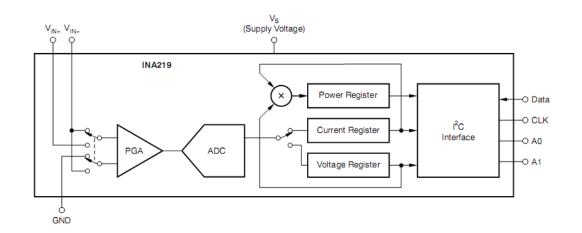


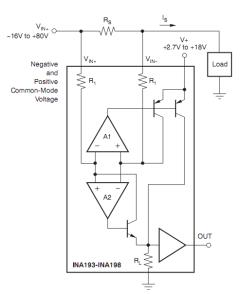


Output

- Op amps, difference amplifiers, and instrumentation amplifiers have voltage outputs
- Current shunt monitors can also have current-output and digitaloutput



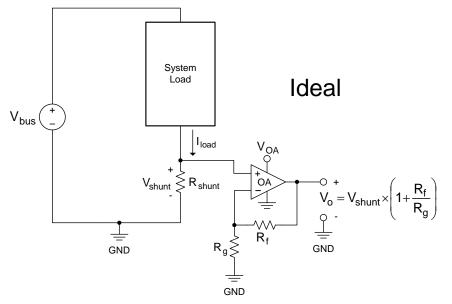




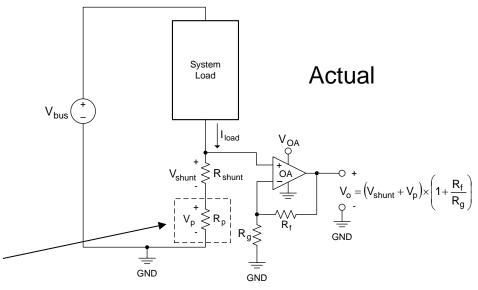


Devices

Op Amp-Low Side Only

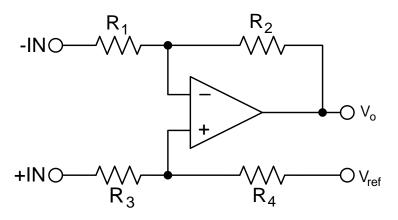


- Very large open-loop gain
- •Must have feedback, so the input will be single-ended
- •Therefore only useful on low-side where Vcm≈GND
- Beware of PCB layout parasitics

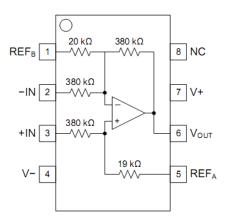


Parasitic impedance to ground introduces error

Difference Amplifier



INA149

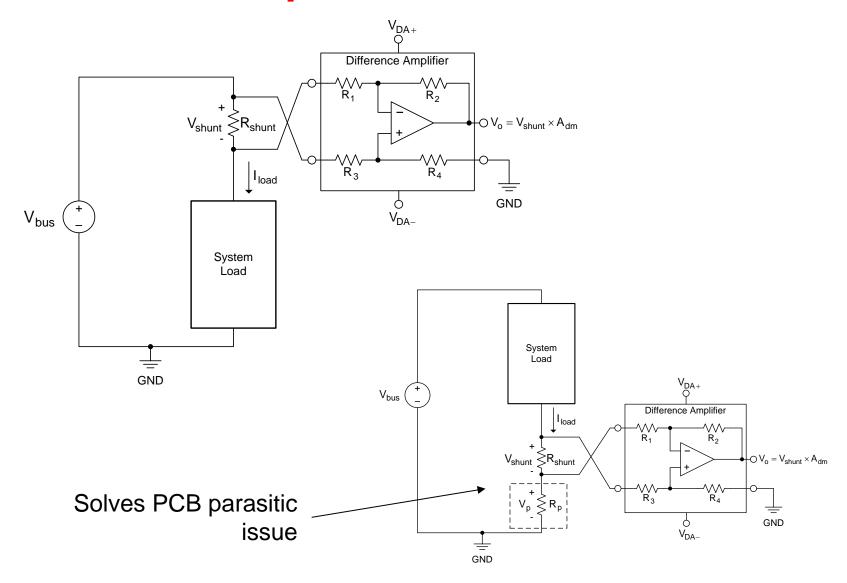


- Can be used for either high or lowside current sensing
- Can tolerate very large commonmode voltages (e.g. INA149 Vcm=±275V!)
- This is due to large resistive divider on input pins
- However this resistive network loads the system
- Ensure system impedance is significantly smaller than DA input impedances

INPUT				
Impedance	Differential	800	kΩ	
	Common-mode	200	kΩ	

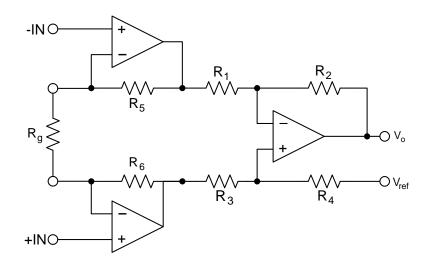


Difference Amplifier

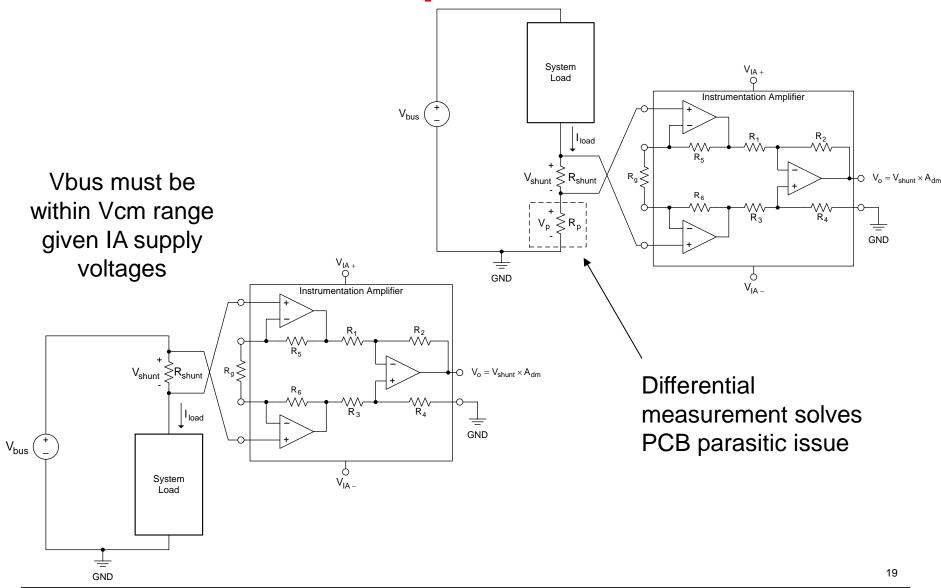


Instrumentation Amplifier

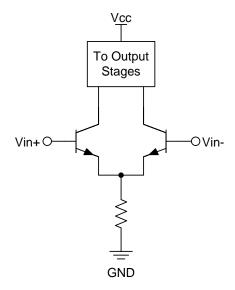
- A three op amp IA is made of a DA with buffered inputs
- Pros
 - Large input impedance
 - Change gain with external resistor
- Cons
 - Common-mode voltage must remain within supply voltage
- Usually used for low-side sensing, but can be used for high-side depending on common-mode voltage



Instrumentation Amplifier

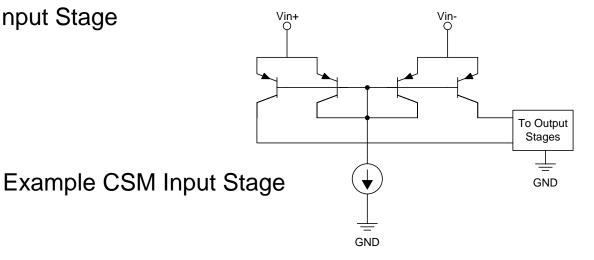


Current Shunt Monitors



Typical Op Amp Input Stage

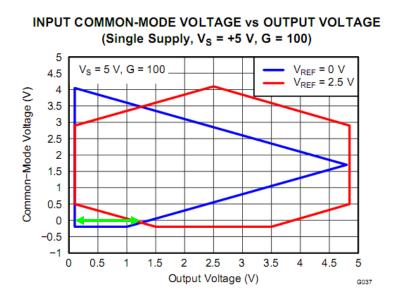
- Unique input stage topologies (e.g. common-base)
- This allows for Vcm values outside of supply voltages AND very large input impedances
- But, maximum Vcm value is currently 80V

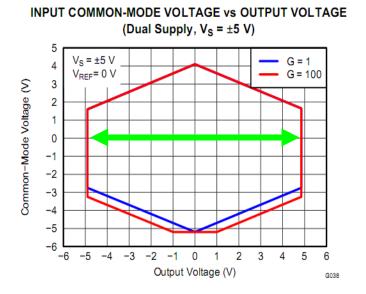




Input and Output Voltage Range

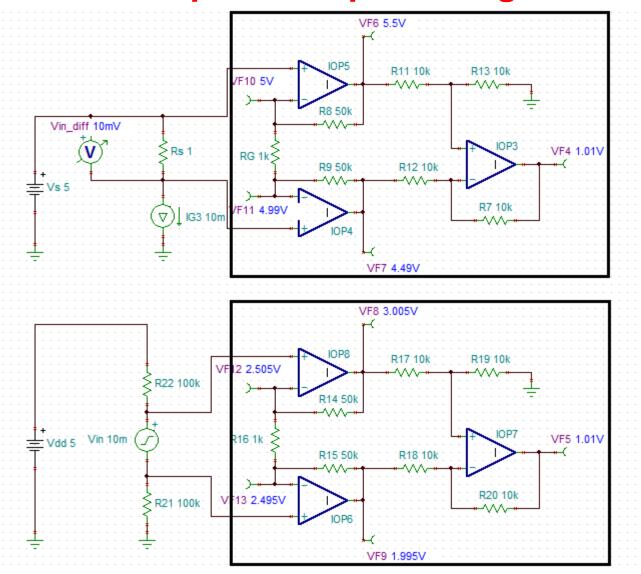
- Always ensure that desired input and output voltage ranges are within datasheet specifications
- Instrumentation amplifiers can be tricky
- For example, can we effectively use the INA826 for a low-side current measurement (Vcm≈0V)?





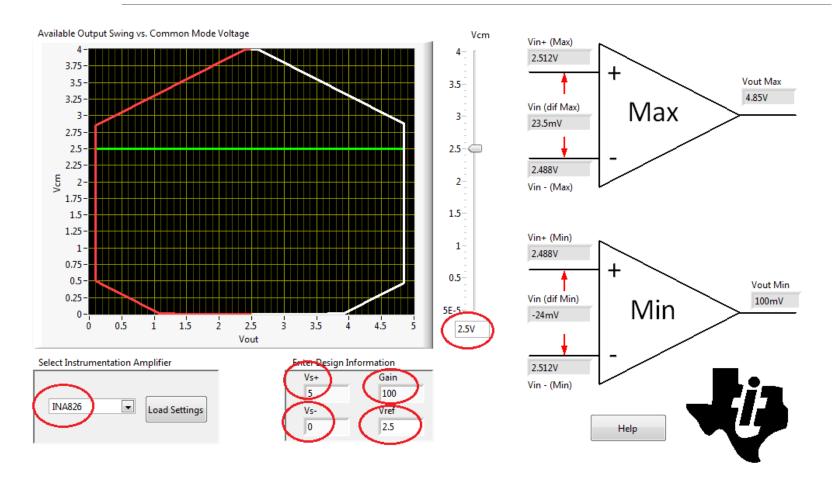


Reasons Behind Input & Output Voltage Limitations





Instrumentation Amplifier Output Swing vs Common-Mode Voltage

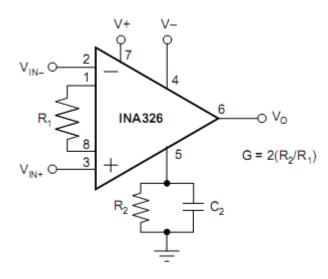


http://www.ti.com/tool/ina-cmv-calc

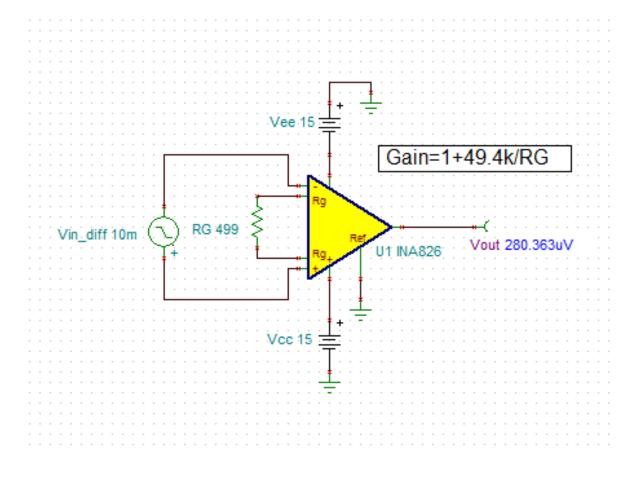


Unique Topologies

- Some instrumentation amplifiers have unique topologies that allow for RRIO on a single supply!
- INA326
 - Input voltage range (V-)-0.02 to (V+)+0.1
 - Output swings to within 75mV over temperature! (5mV typical)
 - Possible drawback: 1kHz BW

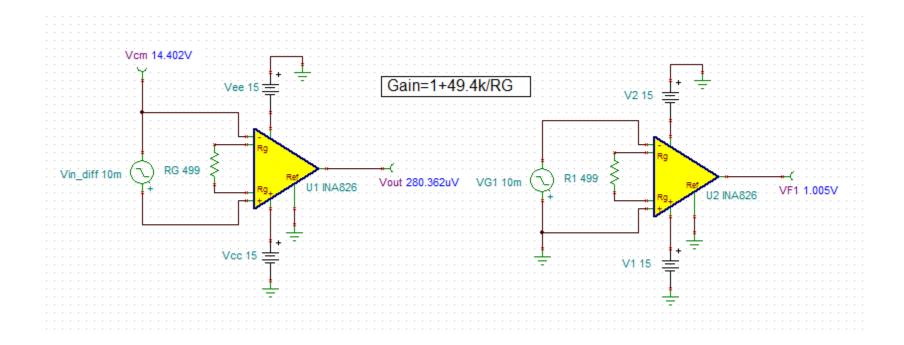


Instrumentation Amplifier Most frequent Simulation Issue





Common-Mode Voltage Problems



Summary

	Vcm≈0V	0V <vcm<vdevice< th=""><th>Vcm>Vdevice</th></vcm<vdevice<>	Vcm>Vdevice
Small Load Current	Op Amp IA CSM	IA CSM	CSM
Large Load Current	Op Amp DA IA CSM	IA DA CSM	DA CSM

Questions?

Accuracy

Accuracy

- Definition
 - Worst case

$$\varsigma_{\text{worst-case}}(\%) = 100 - \sum_{1}^{n} e_{n}$$

Probable (Root-sum-square)

$$\varsigma_{RSS}(\%) = 100 - \sqrt{\sum_{1}^{n} e_{n}^{2}}$$

Error Sources

Description	Referred to
Input offset voltage (V_{os})	Input
Offset voltage drift $\left(\frac{\Delta V_{os}}{\Delta T}\right)$	Input
Offset voltage shift $\left(\frac{\Delta V_{os}}{\Delta t}\right)$	Input
Gain error (%)	Output
Common-mode rejection (dB)	Input
Power supply rejection (dB)	Input
Input offset current $\left(I_{\scriptscriptstyle O\!S}\right)$	Input
Shunt resistor tolerance (%)	Input



Input Offset Voltage (Vos)

- Definition
 - "The DC voltage that must be applied between the input terminals to force the quiescent DC output voltage to zero or some other level, if specified."
- Typically the largest source of error
- Error is calculated with respect to the ideal voltage across the shunt resistor (Vshunt)
- Example (INA170)
 - Vos(max)=1mV
 - Iload=5A (nominal)
 - Rshunt= $1m\Omega$

How do we decrease this error?

- Decrease Vos(max)
- Increase Vshunt

$$e_{V_{os}} = \frac{V_{os(max)}}{V_{shunt}} \times 100 = \frac{V_{os(max)}}{I_{load} \times R_{shunt}} \times 100 = \frac{1mV}{5mV} \times 100 = 20\%$$



Common-mode Rejection Ratio (CMRR)

- Measure of a device's ability to reject common-mode signals
- Otherwise the common-mode signals can manifest themselves into differential signals which add to the error
- Specified one of two ways
 - Linear: μV/V
 - Worst case is the maximum value
 - Logarithmic: dB
 - Worst case is the minimum value
- Need the following to calculate error
 - Worst case specification
 - Common-mode test condition from datasheet (Vcm-pds)
 - System common-mode voltage (Vcm-sys)



CMRR Example

Vcm-sys=50V

Device: INA170

Rshunt=1mΩ

ELECTRICAL CHARACTERISTICS

At $T_A = -40$ °C to +85°C, $V_S = 5V$, $V_{IN}^+ = 12V$, $R_{OUT} = 25k\Omega$, unless otherwise noted.

		INA170EA			
PARAMETER	CONDITION	MIN	TYP	MAX	UNITS
INPUT Full-Scale Sense (Input) Voltage Common-Mode Input Range Common-Mode Rejection	w to we minimize V _{IN} = +2.7V to +60V, V _{SENSE} = 50mV	this er	ror? ₁₀₀	500 +60	mV V dB

- Iload=5A (nominal)
- First, convert 100dB to linear scale

$$CMRR_{INA170} = \frac{1}{100 \frac{CMRR_{(dB)min}}{20}} = \frac{1}{100 \frac{100 \text{ dB}}{20}} = 10 \frac{\mu V}{V}$$

Now calculate error contribution

$$e_{CMRR} = \frac{\left| \left| V_{cm-pds} - V_{cm-sys} \right| \right| \times CMRR_{INA170}}{V_{shunt}} \times 100 = \frac{\left| \left| 12V - 50V \right| \right| \times 10 \frac{\mu V}{V}}{5mV} \times 100 = 7.6\%$$



Power Supply Rejection Ratio (PSRR)

- Measure of the change in Vos created by a change in power supply voltage
- Calculation very similar to CMRR
- Need the following to calculate error
 - Worst case specification
 - Supply voltage test condition from datasheet (Vs-pds)
 - Device's supply voltage (Vs-sys)



PSRR Example

ELECTRICAL CHARACTERISTICS At $T_A = -40^{\circ}\text{C}$ to +85°C, $\frac{\text{V}_8}{\text{S}} = \frac{5\text{V}_1}{\text{V}_1^*} = 12\text{V}$, $R_{\text{OUT}} = 25\text{k}\Omega$, unless otherwise noted

Vs-sys=30V

Device: INA170

Rshunt=1mΩ

		INA170EA			
PARAMETER	CONDITION	MIN	TYP	MAX	UNITS
INPUT					
Full-Scale Sense (Input) Voltage	$V_{SENSE} = V_{IN}^+ - V_{IN}^-$		100	500	mV
Common-Mode Input Range		+2.7		+60	V
Common-Mode Rejection	$V_{IN}^{+} = +2.7V$ to +60V, $V_{SENSE} = 50mV$	100	120		dB
Offset Voltage(1) RTI	321.02		±0.2	±1	mV
vs Temperature	T _{MIN} to T _{MAX}		1		μV/°C
vs Power Supply	V+ = +2.7V to +60V, Version = 50mV		0.1	10	uV/V

- Iload=5A (nominal)
- PSRR already specified in linear scale

$$e_{PSRR} = \frac{\left(\left| V_{s-pds} - V_{s-sys} \right| \right) \times PSRR_{INA170}}{V_{shunt}} \times 100 = \frac{\left(\left| 5V - 30V \right| \right) \times 10 \frac{\mu V}{V}}{5 \text{mV}} \times 100 = 5\%$$

How do we reduce this error term?



Other Errors

- Gain error
 - Usually listed in datasheet as a percentage
- Shunt resistor tolerance
 - Usually given as a percentage. Beware of temperature drift, though.
- Vos drift
 - Usually listed in datasheet as μV/°C
 - Multiply specification by maximum deviation from 25C
- Vos shift
 - Change in Vos due to time
 - Usually not specified. Most likely never guaranteed.
 - Rule of thumb: In 10 years, Vos may shift no more than the Vos(max) specification.
 - This is in addition to the device's initial Vos specification.



Putting It All Together

- Let's calculate the error of our example due to Vos, CMRR, and PSRR
- 20% error due to Vos (initial)
- 7.6% error due to CMRR
- 5% error due to PSRR

$$e_{total-worst-case}(\%) = \sum_{1}^{n} e_n = 20 + 7.6 + 5 = 32.6\%$$

$$e_{total-RSS}(\%) = \sqrt{\sum_{1}^{n} e_{n}^{2}} = \sqrt{20^{2} + 7.6^{2} + 5^{2}} = 21.97\%$$

Note: This is for the nominal load current. What if 2A<lload<6A?



PCB Layout and Troubleshooting



Accuracy Revisited

- System-Level Errors revisited
- Notice these are all specifications
- Are they under the control of the designer?
- New
 - Designer Control
 - Input Bias Current (Ib)
 - Vos-pcb
- Ib is defined as the average of the currents into the two input terminals with the output at the specified level.

Description	Referred to
Input offset voltage (Vos)	Input
Offset voltage drift $\left(\frac{\Delta V_{OS}}{\Delta T}\right)$	Input
Offset voltage shift $\left(\frac{\Delta V_{OS}}{\Delta t}\right)$	Input
Gain Error (%)	Output
Common-mode rejection (dB)	Input
Power supply rejection (dB)	Input
Input offset current (I _{OS})	Input
Shunt resistor tolerance (%)	Input

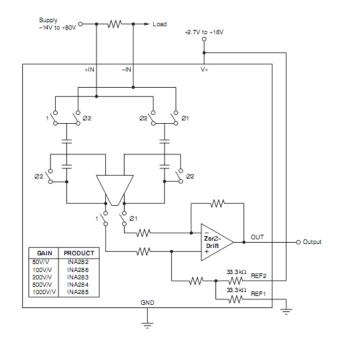


Example Design

- Requirements
 - Common-mode voltage (Vcm): 70V
 - Available supply for differential amplifier (Vs): 5V
 - Load current range: 5A<lload<10A
 - Unidirectional
 - High accuracy
- Can't use an op amp due to Vcm
- Can't use an IA due to Vcm
- High accuracy->look at CSMs
- No mention of bandwidth->assume DC measurement

INA282

- -14V<Vcm<80V</p>
- Vos= 70μ V
- 2.7V<Vs<18V
- Bi-directional





Sizing the Shunt Resistor

- We need the following to size the shunt resistor
 - Load current range
 - Available supply voltage
- For this example
 - 5A<lload<10A</p>
 - Vs=5V
- Strategy
 - Obtain output voltage range from datasheet
 - Refer it back to the input by dividing by the device's gain
 - Use load range minimum and maximum to find range of acceptable shunt resistor values



Sizing the Shunt Resistor

- Input and Output Range-INA282
 - Output Range: GND+40mV<Vout<Vs-0.4V
 - Since Vs=5V, 40mV<Vout<4.6V
 - Refer to input by dividing by gain (INA282 Gain=50V/V)
 - Input Range: 800μV<Vin<92mV
- Calculate maximum and minimum values for the shunt resistance

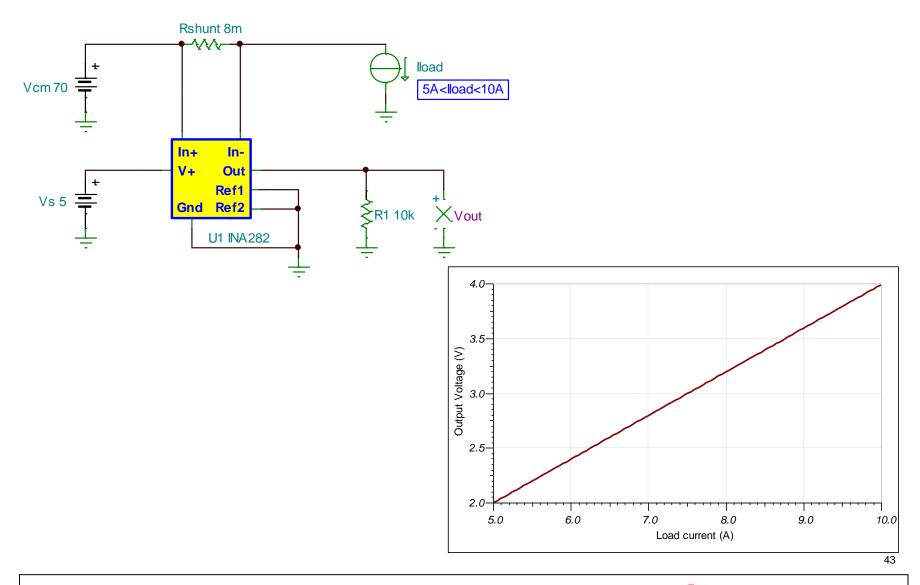
$$R_{shunt-max} = \frac{V_{in-max}}{I_{load-max}} = \frac{92mV}{10A} = 9.2m\Omega$$

$$R_{shunt\,-min} = \frac{V_{in-min}}{I_{load\,-min}} = \frac{800\,\mu V}{5A} = 0.16 m\Omega$$

- Note: Rshunt value is directly related to both power and accuracy
- So, use the largest Rshunt that your system can tolerate



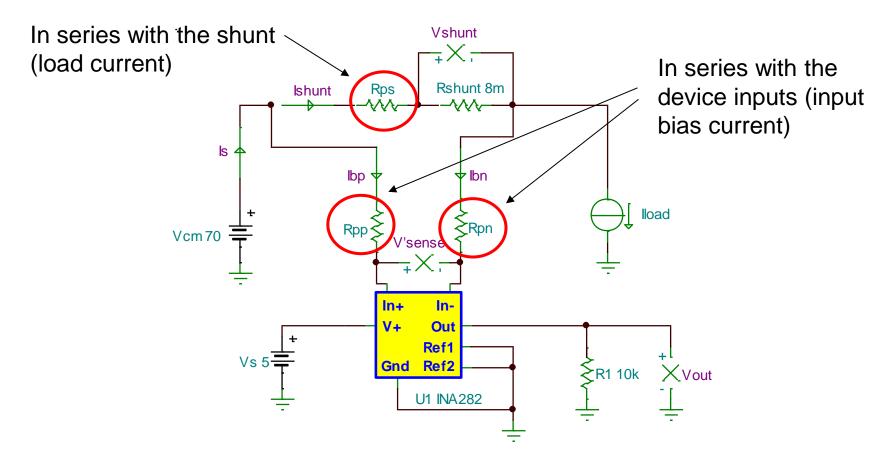
Example Simulation





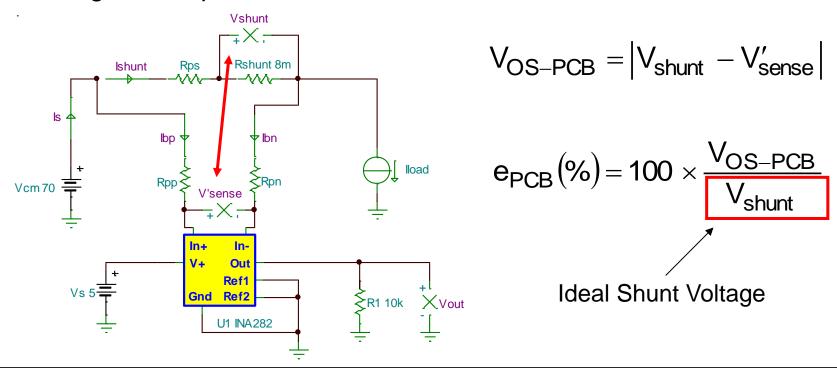
PCB Parasitics

There are 3 parasitic resistances that can affect the accuracy



PCB Parasitics

- Ideally Vshunt=Vsense
- Vsense is the voltage <u>at the pins</u> of the device
- However, the parasitics cause Vshunt≠Vsense, so we will rename the voltage at the pins to V'sense

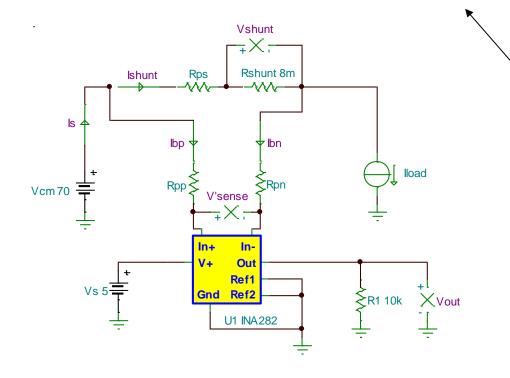


PCB Parasitics

Input bias currents may or may not induce an error

If we solve for V'sense we get

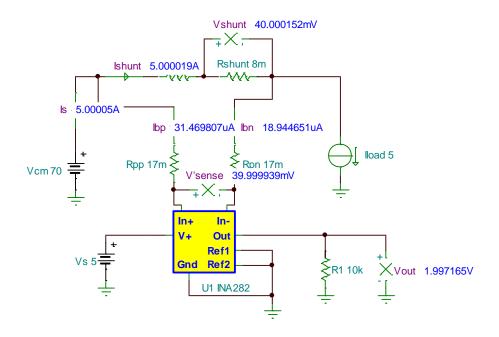
$$V_{sense}' = V_{shunt} + \left(I_{shunt}R_{ps} + \left(I_{bp}R_{pp} - I_{bn}R_{pn}\right)\right)$$



ANY parasitic resistance in series with the shunt resistor will induce an error

Balanced Rpn and Rpp Error

• One-ounce copper input traces of 350mils in length and 10mils wide have an impedance of approximately $17m\Omega$.

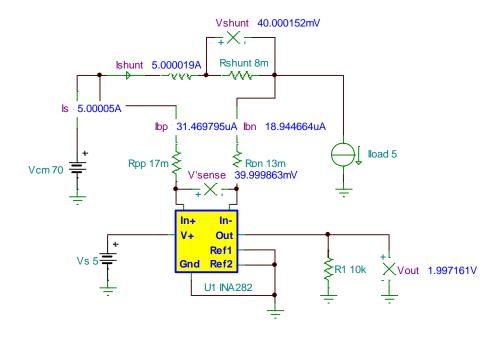


$$e_{PCB} = 100 \times \frac{V_{OS-PCB}}{V_{shunt}} = 100 \times \frac{\left|V_{shunt} - V_{sense}'\right|}{V_{shunt}} = 532.5 \mu\%$$



Unbalanced Rpn and Rpp Error

Assume Rpp=350mils and Rpn=275mils (13mΩ)



$$e_{PCB} = 100 \times \frac{V_{OS-PCB}}{V_{shunt}} = 100 \times \frac{\left|V_{shunt} - V_{sense}'\right|}{V_{shunt}} = 722.5 \mu\%$$

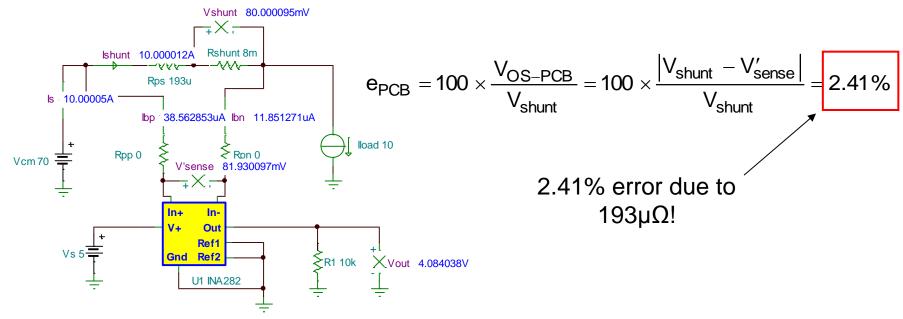
Rpn and Rpp Error Observations

- These errors are generally not significant
- Placing the device and shunt on opposite sides of the board can exacerbate the error due to vias and temperature drift
- Attempting to size the input traces such that lbp*Rpp=Ibn*Rpn is not recommended
 - Ib can vary part-to-part, wafer-to-wafer, and lot-to-lot.
 - It can also vary based on system parameters such as common-mode voltage and power supply
- PCB Layout Recommendations
 - Make the input traces as short as possible
 - Make the input traces as balanced as possible
 - Place the current sensing device and shunt on the same side of the PCB



Rps Error

- ANY resistance in series with the shunt will induce an error
- One-ounce copper trace of 10mils in length and 25mils wide has an impedance of approximately 193μΩ.
 - Recall that Rps is in the high-current path



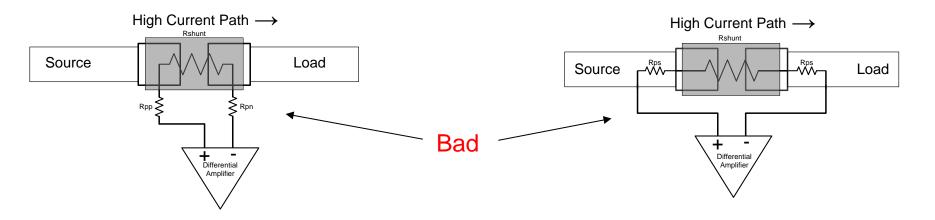
How did we get resistance in series with Rshunt? Rshunt not Kelvin-connected!



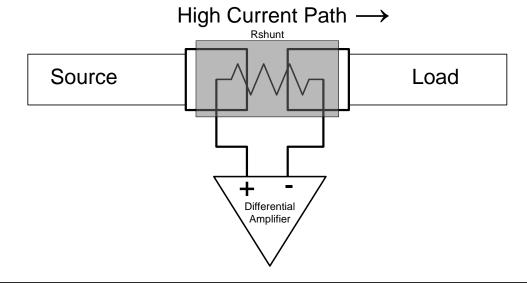
Rps Error Example



PCB Layout Summary



Good! Kelvin-connection

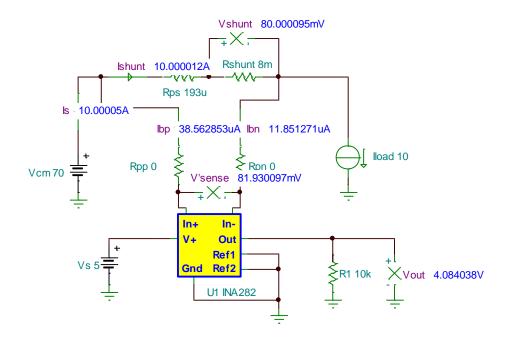




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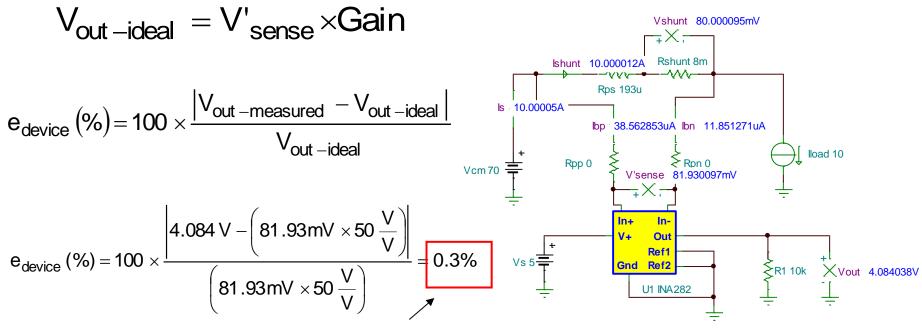
Rps Error

- Many engineers verify this circuit by comparing the output (4.084V) to the product of the shunt voltage (80mV) and the device's gain (50V/V)
- This shows 84mV of error, which is unacceptable for the INA282.
- Conclusion: The device's gain is incorrect…let's do a failure analysis!



Rps Error

- Not so fast!
- To determine error introduced by the device you must use <u>V'sense</u>



Not the device...no FA required.

PCB Layout & Troubleshooting Summary

- Always ensure that the shunt resistor is Kelvin-connected
- Make the input traces as short as possible
- Make the input traces as balanced as possible
- Place the current sensing device and shunt on the same side of the PCB
- To determine device error, look at voltage across device pins (Vsense)
- Check to see if device is within specification for given application
 - Quickly calculate error referred to output due to Vos, CMRR, and PSRR



Questions?

Additional Reading

- Current Sensing Fundamentals
- Current Sensing Devices
- Current Sensing Accuracy
- Current Sensing Layout & Troubleshooting



Devices

- For samples of the devices mentioned in this presentation, please follow the appropriate link
 - INA170, CSM, voltage output, 2.7V<Vcm<60V, Vos=1mV(max)
 - INA282, CSM, voltage output, -14V<Vcm<80V, Vos=70uV(max)
 - <u>INA326</u>, IA, RRI/O, Vos=100uV(max)
 - INA826, IA, RRO, Iq=200uA(typ), 2.7V<Vsupply<36V
 - <u>INA149</u>, DA, Vcm=+/-275V, unity gain
 - <u>INA219</u>, CSM, digital, 0V<Vcm<26V, Vos=50uV(max)
 - <u>INA138/168</u>, CSM, current output, 2.7V<Vcm<36V/60V, Vos=1mV(max)
 - INA193, CSM, voltage output, -16V<Vcm<80V, Vos=2mV(max)



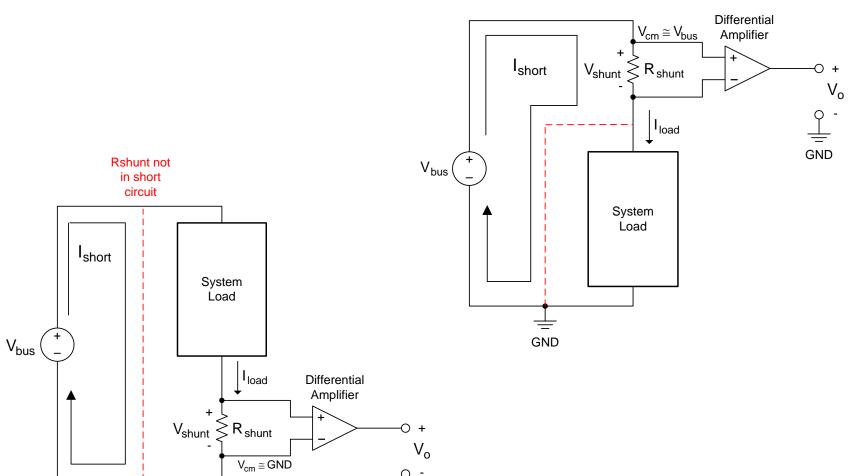
Backup



Load Short

H GND

Rshunt in short circuit



GND



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